

MOSFETs Silicon N-channel MOS (U-MOSIX-H)

TPHR9203PL

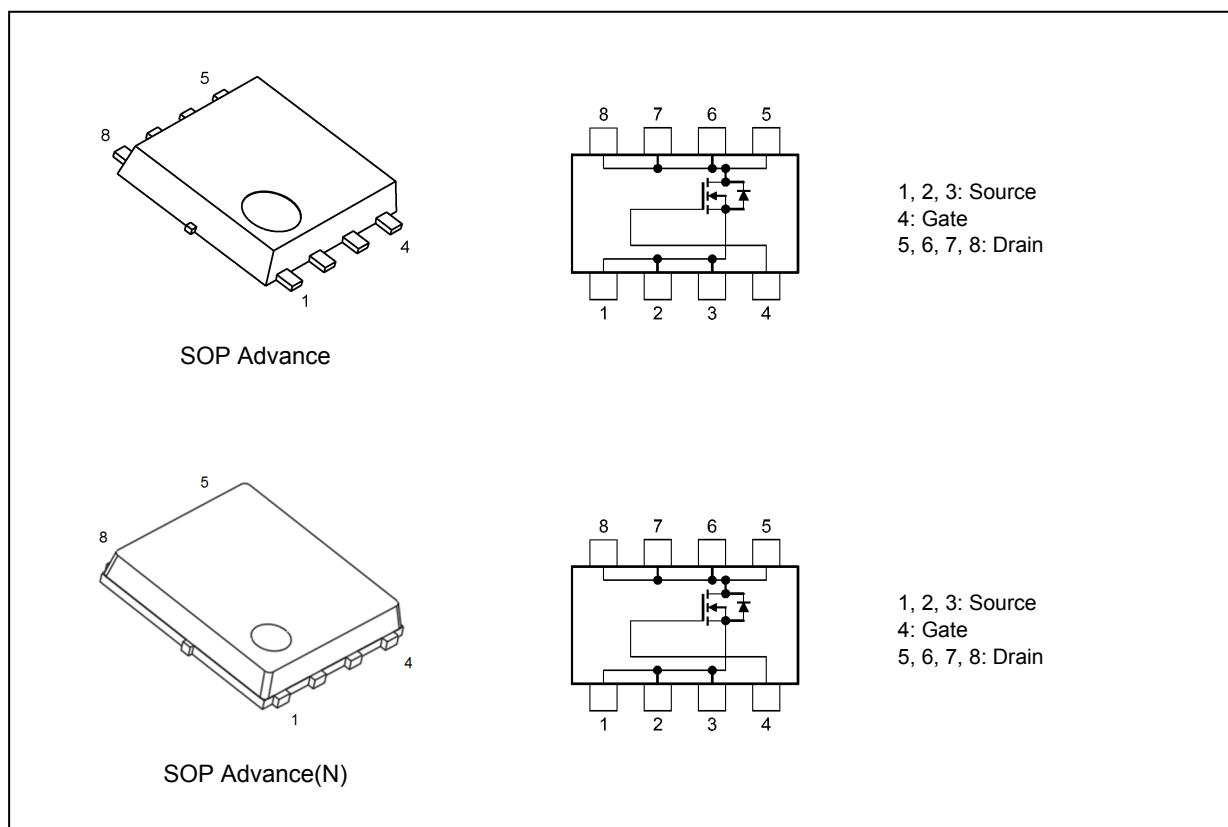
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 19 \text{ nC}$ (typ.)
- (3) Small output charge: $Q_{OSS} = 51 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 0.61 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (5) Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A}$ (max) ($V_{DS} = 30 \text{ V}$)
- (6) Enhancement mode: $V_{th} = 1.1 \text{ to } 2.1 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 0.5 \text{ mA}$)

3. Packaging and Internal Circuit



The package can be selected according to your preference. For details, please contact your TOSHIBA sales representative.

Start of commercial production

2016-06

4. Absolute Maximum Ratings (Note) ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	30	V
Gate-source voltage (Note 1)	V_{GSS}	± 20	
Drain current (DC) ($T_c = 25\text{ }^{\circ}\text{C}$) (Note 2)	I_D	150	A
Drain current (DC) (Silicon limit) (Note 2), (Note 3)	I_D	280	
Drain current (pulsed) ($t = 100\text{ }\mu\text{s}$) (Note 2)	I_{DP}	500	
Power dissipation ($T_c = 25\text{ }^{\circ}\text{C}$)	P_D	132	W
Power dissipation (Note 4)	P_D	3.0	
Power dissipation (Note 5)	P_D	0.96	
Single-pulse avalanche energy (Note 6)	E_{AS}	108	mJ
Single-pulse avalanche current (Note 6)	I_{AS}	120	A
Channel temperature	T_{ch}	175	$^{\circ}\text{C}$
Storage temperature	T_{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance ($T_c = 25\text{ }^{\circ}\text{C}$)	$R_{th(ch-c)}$	1.13	$^{\circ}\text{C/W}$
Channel-to-ambient thermal resistance ($T_a = 25\text{ }^{\circ}\text{C}$) (Note 4)	$R_{th(ch-a)}$	50	
Channel-to-ambient thermal resistance ($T_a = 25\text{ }^{\circ}\text{C}$) (Note 5)	$R_{th(ch-a)}$	156	

Note 1: +20 V/-16 V ensured at DC condition.

-20 V ensured at pulse condition (duty 5 %).

Note 2: Ensure that the channel temperature does not exceed 175 $^{\circ}\text{C}$.

Note 3: Limited 150 A by package capability.

Note 4: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 5: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 6: $V_{DD} = 24\text{ V}$, $T_{ch} = 25\text{ }^{\circ}\text{C}$ (initial), $L = 5.8\text{ }\mu\text{H}$, $I_{AS} = 120\text{ A}$

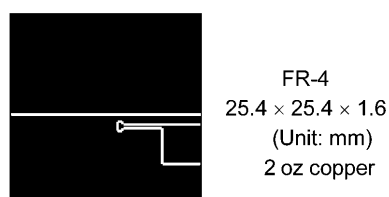


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

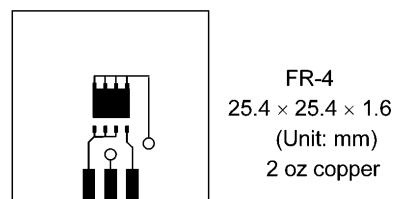


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 0.1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = 30\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}$, $V_{GS} = 0\text{ V}$	30	—	—	V
Drain-source breakdown voltage (Note 7)	$V_{(BR)DSX}$	$I_D = 10\text{ mA}$, $V_{GS} = -20\text{ V}$	15	—	—	
Gate threshold voltage	V_{th}	$V_{DS} = 10\text{ V}$, $I_D = 0.5\text{ mA}$	1.1	—	2.1	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 4.5\text{ V}$, $I_D = 50\text{ A}$	—	0.91	1.29	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}$, $I_D = 50\text{ A}$	—	0.61	0.92	

Note 7: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = 15\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	5800	7540	pF
Reverse transfer capacitance	C_{rss}		—	190	335	
Output capacitance	C_{oss}		—	1750	—	
Gate resistance	r_g	—	—	0.5	1.0	Ω
Switching time (rise time)	t_r	See Figure 6.2.1	—	8	—	ns
Switching time (turn-on time)	t_{on}		—	20	—	
Switching time (fall time)	t_f		—	18	—	
Switching time (turn-off time)	t_{off}		—	71	—	

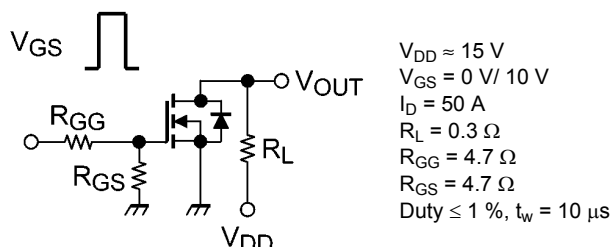


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 15\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 50\text{ A}$	—	81	—	nC
		$V_{DD} \approx 15\text{ V}$, $V_{GS} = 4.5\text{ V}$, $I_D = 50\text{ A}$	—	38	—	
Gate-source charge 1	Q_{gs1}	$V_{DD} \approx 15\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 50\text{ A}$	—	17	—	
Gate-drain charge	Q_{gd}		—	11	—	
Gate switch charge	Q_{SW}		—	19	—	
Output charge	Q_{oss}	$V_{DS} = 15\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	51	—	

6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 8)	I _{DRP}	(t = 100 μs)	—	—	500	A
Diode forward voltage	V _{DSF}	I _{DR} = 150 A, V _{GS} = 0 V	—	—	-1.2	V
Reverse recovery time	t _{rr}	V _R = 15 V, I _{DR} = 37.5 A,	—	46	—	ns
Reverse recovery charge	Q _{rr}	V _{GS} = 0 V, -dI _{DR} /dt = 100 A/μs	—	44	—	nC

Note 8: Ensure that the channel temperature does not exceed 175 °C.

7. Marking

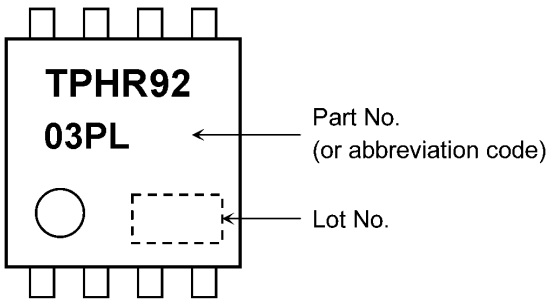


Fig. 7.1 Marking

8. Characteristics Curves (Note)

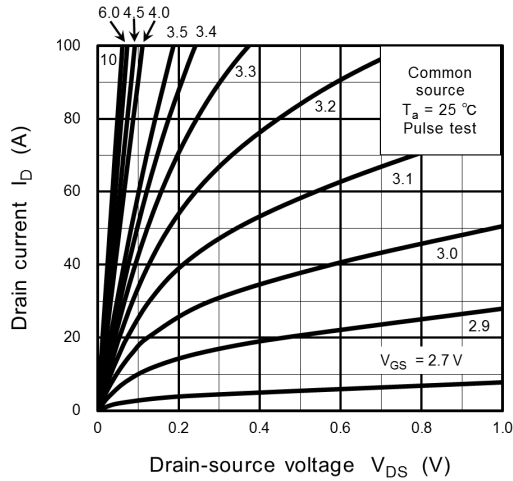


Fig. 8.1 $I_D - V_{DS}$

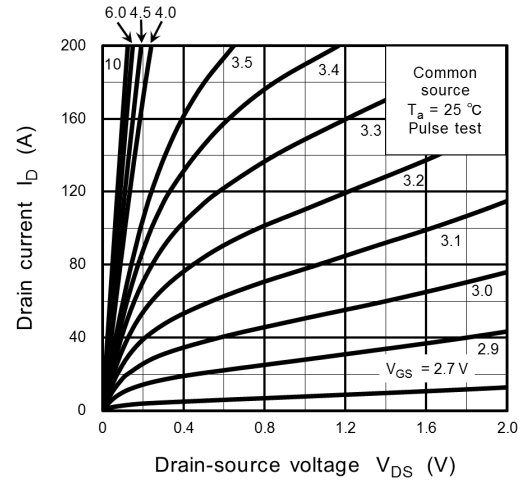


Fig. 8.2 $I_D - V_{DS}$

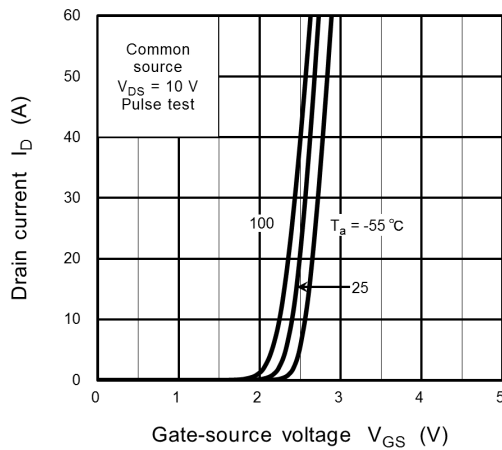


Fig. 8.3 $I_D - V_{GS}$

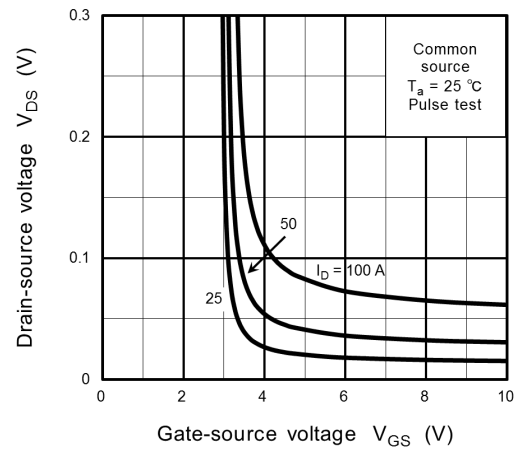


Fig. 8.4 $V_{DS} - V_{GS}$

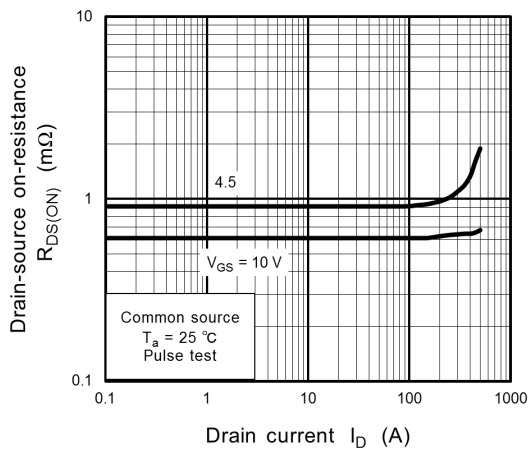


Fig. 8.5 $R_{DS(ON)} - I_D$

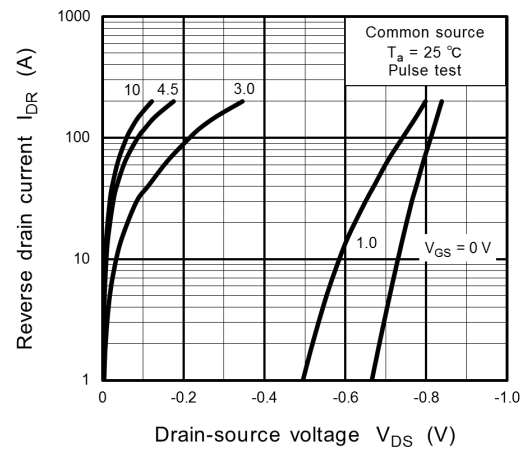


Fig. 8.6 $I_{DR} - V_{DS}$

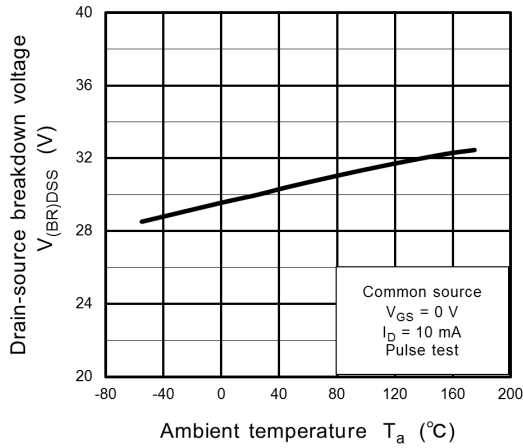


Fig. 8.7 $V_{(BR)DSS} - T_a$

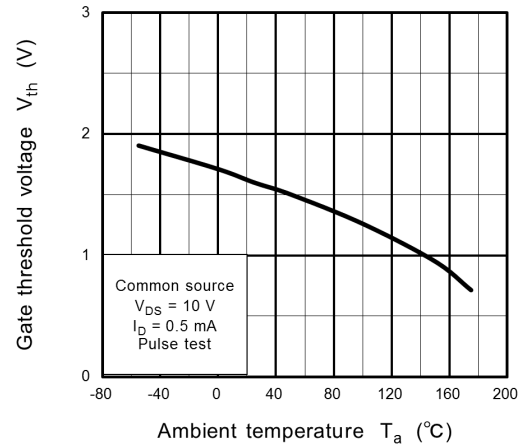


Fig. 8.8 $V_{th} - T_a$

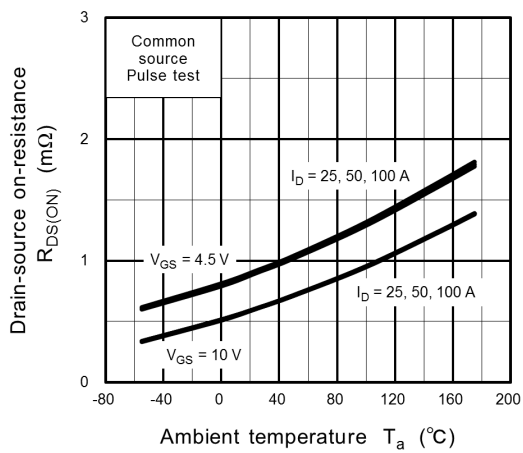


Fig. 8.9 $R_{DS(ON)} - T_a$

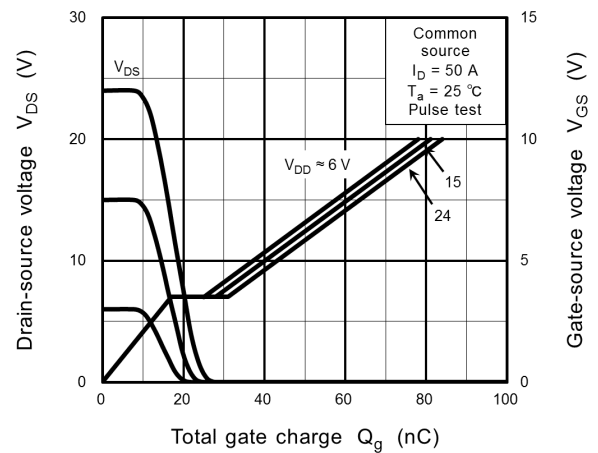


Fig. 8.10 Dynamic Input/Output Characteristics

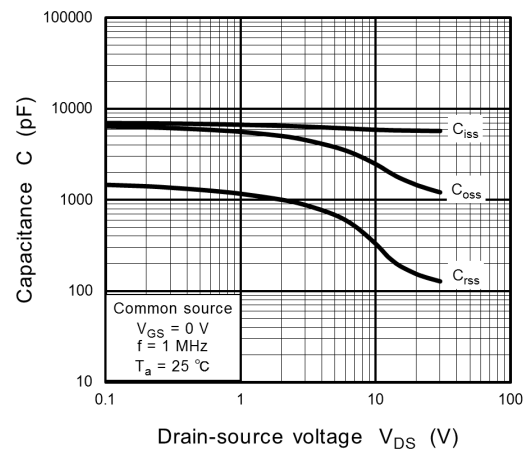


Fig. 8.11 Capacitance - V_{DS}

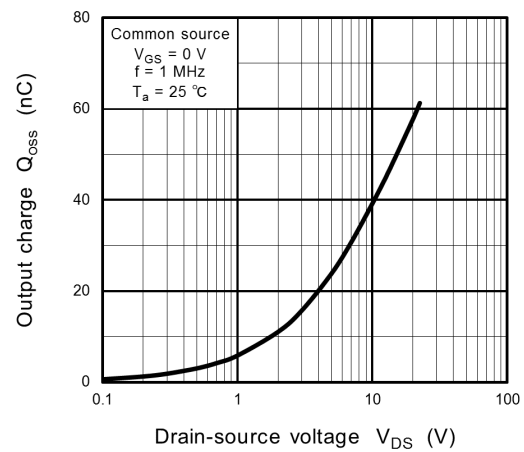


Fig. 8.12 $Q_{oss} - V_{DS}$

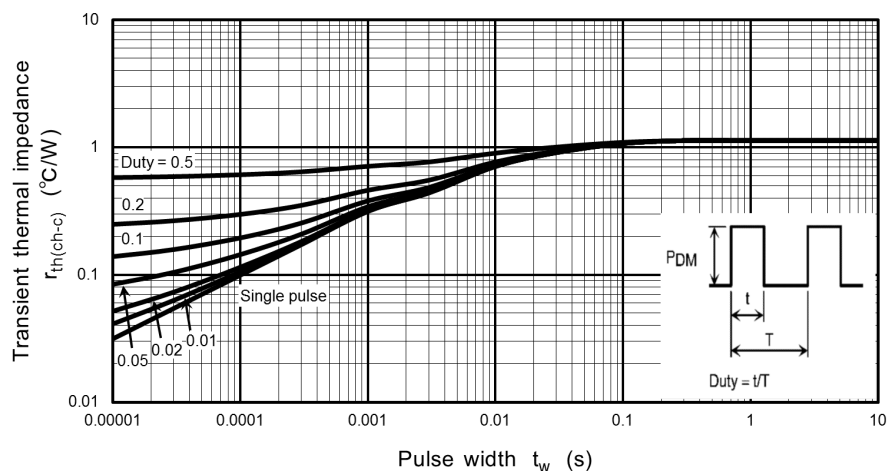


Fig. 8.13 $r_{th} - t_w$
(Guaranteed Maximum)

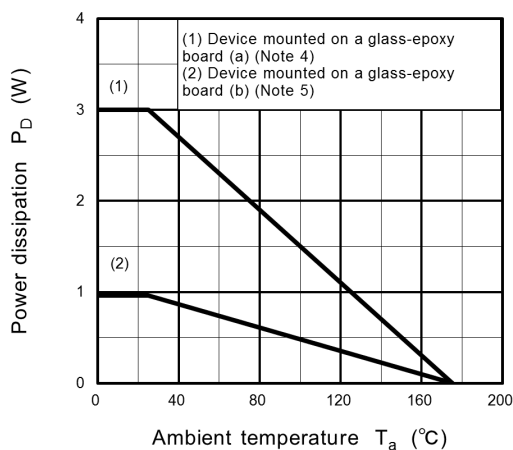


Fig. 8.14 $P_D - T_a$
(Guaranteed Maximum)

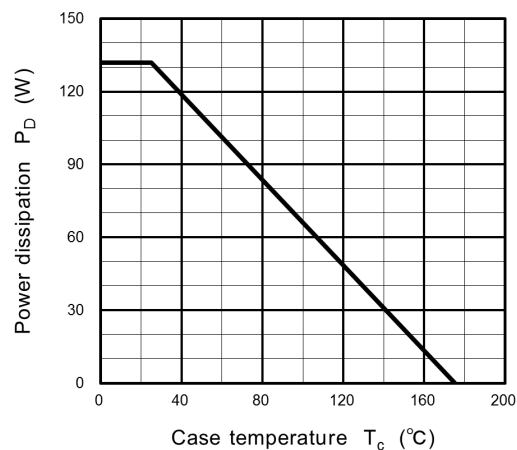


Fig. 8.15 $P_D - T_c$
(Guaranteed Maximum)

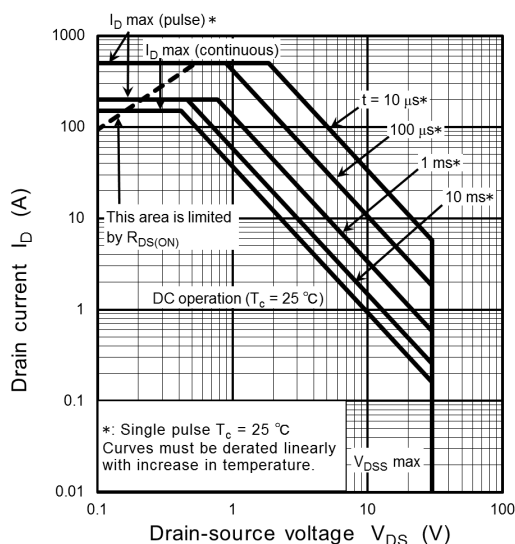
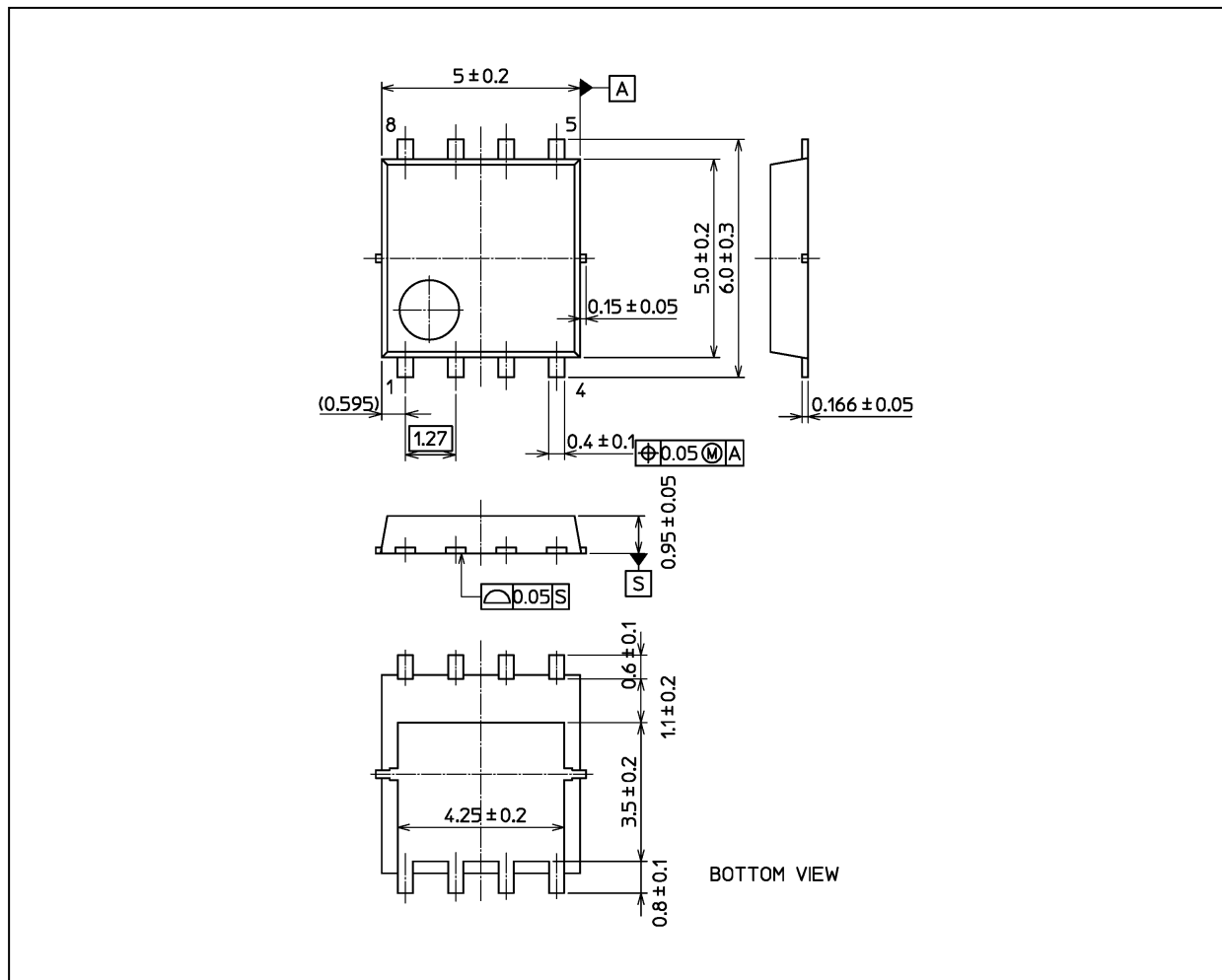


Fig. 8.16 Safe Operating Area
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



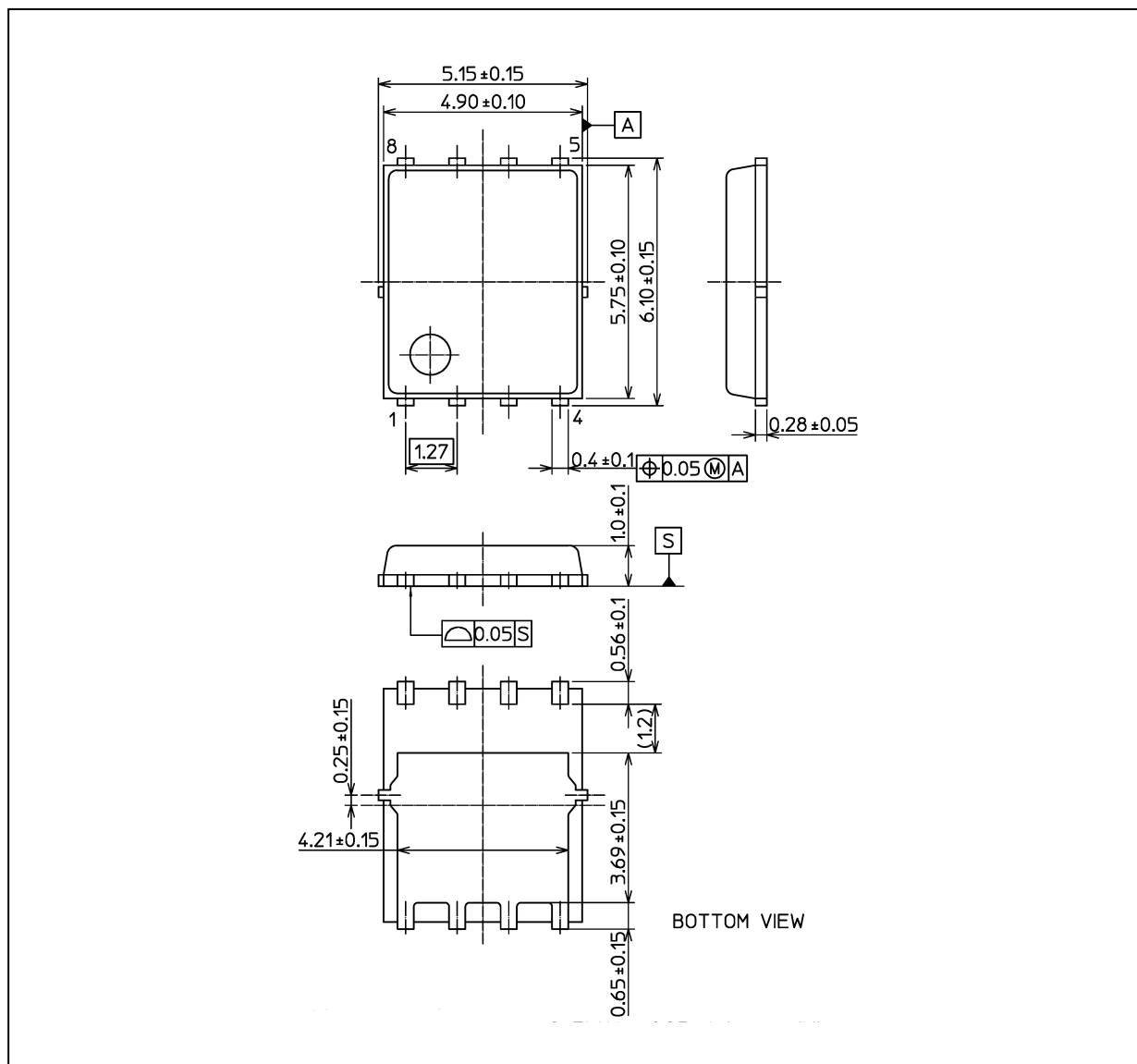
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Weight: 0.079 g (typ.)

Package Name(s)
TOSHIBA: 2-5Q1S
Nickname: SOP Advance

Package Dimensions

Unit: mm



The package can be selected according to your preference. For details, please contact your TOSHIBA sales representative.

Weight: 0.105 g (typ.)

Package Name(s)
TOSHIBA: 2-5W1A
Nickname: SOP Advance(N)

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